AD7523, AD7533

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勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

Description

The AD7523 and AD7533 are monolithic, low cost, high performance, 8-bit and 10-bit accurate, multiplying digital-to-analog converter (DAC), in a 16 pin DIP.

8-Bit, Multiplying D/A Converters

Intersil' thin film resistors on CMOS circuitry provide 10-bit resolution (8-bit, 9-bit and 10-bit accuracy), with TTL/CMOS compatible operation.

The AD7523 and AD7533s accurate four quadrant multiplication, full military temperature range operation, full input protection from damage due to static discharge by clamps to V+ and GND, and very low power dissipation make it a very versatile converter.

Low noise audio gain controls, motor speed controls, digitally controlled gain and digital attenuators are a few of the wide range of applications of the AD7523 and AD7533.

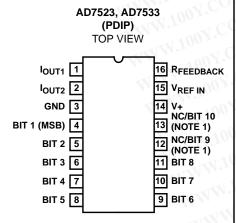
Features

- · 8-Bit, 9-Bit and 10-Bit Linearity
- Low Gain and Linearity Temperature Coefficients
- Full Temperature Range Operation
- Static Discharge Input Protection
- TTL/CMOS Compatible
- Supply Range.....+5V to +15V
- Fast Settling Time at 25°C 150ns (Max)
- Four Quadrant Multiplication
- AD7533 Direct AD7520 Equivalent

Ordering Information

PART NUMBER	LINEARITY (INL, DNL)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
AD7523JN, AD7533JN	0.2% (8-Bit)	0 to 70	16 Ld PDIP	E16.3
AD7523KN, AD7533KN	0.1% (9-Bit)	0 to 70	16 Ld PDIP	E16.3
AD7523LN, AD7533LN	0.05% (10-Bit)	0 to 70	16 Ld PDIP	E16.3

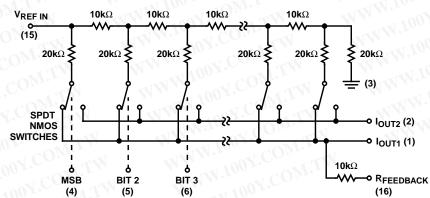
Pinout



NOTE:

1. NC for AD7523 only.

Functional Block Diagram



NOTE: Switches shown for digital inputs "High"

AD7523, AD7533

Absolute Maximum Ratings Thermal Information Supply Voltage (V+ to GND)..... Thermal Resistance (Typical, Note 1) θ_{JA} (oC/W) Digital Input Voltage RangeV+ to GND Maximum Junction Temperature (Plastic Package) 150°C Output Voltage Compliance -100mV to V+ Maximum Storage Temperature-65°C to 150°C Maximum Lead Temperature (Soldering 10s).....300°C **Operating Conditions** Temperature Range JN, KN, LN Versions CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation

of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

1. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications V+ = +15V, $V_{REF} = +10V$, $V_{OUT1} = V_{OUT2} = 0V$, Unless Otherwise Specified

PARAMETER		TEST CONDITIONS	AD7523				AD7533				
			T _A 25°C		T _A MIN-MA	N-MAX	TA	T _A 25°C		TA MIN-MAX	
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
SYSTEM PERFORMA	NCE	NTW WITH	10	OVICE	ow.		4	N VI	N.100	y	MIT
Resolution	Y.CO	WY WY	8	00 ¥.C	8	LIN	10	11-11	10	ON:	Bits
Nonlinearity J	$-10V \le V_{REF} \le +10V$ $V_{OUT1} = V_{OUT2} = 0V$	MM	±0.2	COJ	±0.2	-	±0.2	NW.	±0.2	% of FSR	
	K, T	(Notes 2, 3, 6)	NW	±0.1	Y.CO	±0.1	N -	±0.1	W-W	±0.1	% of FSR
	700	COM.TW	M.M.	±0.05	ON.C	±0.05	W.	±0.05		±0.05	% of FSR
Monotonicity	W.106	COM	- 11	Guara	inteed	CO_{M}		Guara	anteed	M. In	ov.C
Gain Error	NW.10	All Digital Inputs High (Note 3)	- 1	±1.5	100, 100,	±1.8	M.T	±1.4	-1/	±1.8	% of FSR
Nonlinearity Tempco		-10V ≤ V _{REF} ≤ + 10V (Notes 3, 4)	-	±2	W.10	±2	OM.T	±2	- 1	±2	ppm of FSR/ ^o C
Gain Error Tempco		1.100Y.COM.TV	-	±10	NA.	±10		±10	-	±10	ppm of FSR/ ⁰ C
Output Leakage Current (Either Output)		$V_{OUT1} = V_{OUT2} = 0$	N -	±50	N.W.Y	±200	1.CO	±50	- V	±200	nA
DYNAMIC CHARACTE	ERISTICS	M. Too . COM.	- 1		- 111	M. Inc	~√ C'	$0M_{\odot}$	N.		WWW
Power Supply Rejection	n	V+ = 14.0V to 15.0V (Note 3)	LTW	±0.02	W	±0.03	00¥.	±0.005	TW	±0.008	% of FSR/% of ΔV+
Output Current Settling	Time	To 0.2% of FSR, $R_L = 100\Omega$ (Note 4)	M.I	150	-	200	1.100	600	-	800	ns
Feedthrough Error		V _{REF} = 20V _{P-P} , 200kHz Sine Wave, All Digital Inputs Low (Note 4)	COM	±1/2	-	±1	-	±0.05	-	±0.1	LSB
REFERENCE INPUTS		MM, 100X				•					_
Input Resistance (Pin 1	5)	All Digital Inputs High I _{OUT1} at Ground (Note 4)	5	-	5	-	5	-	5	-	kΩ
			-	20	-	20	-	20	-	20	kΩ
Temperature Coefficient		1	-	-500	-	-500	-	-300	-	-300	ppm/ ^o C

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Electrical Specifications V+ = +15V, $V_{REF} = +10V$, $V_{OUT1} = V_{OUT2} = 0V$, Unless Otherwise Specified (Continued)

PARAMETER		AD7523				AD7533				
		T _A 25°C		T _A MIN-M	N-MAX	T _A 25°C		T _A MIN-MAX		1
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
	MM. 100X.C	·ow.	(M		MAI	N.100	7.0	M^{T}	N.	•
C _{OUT1}	All Digital Inputs High	LOW	100	-	100	W-10	100	OVL	100	pF
C _{OUT2}	(Note 4)		30	-	30	- 1XN 3	35	Mon	35	pF
C _{OUT1}	All Digital Inputs Low	(Co.	30	-	30	N T	35		35	pF
C _{OUT2}	(Note 4)	N.CC	100	N -	100	11/1	100	.0_	100	pF
TV	WWW	nov.C	OF	TVI		MW	100	Y.C.	T.Mc	
/ _{IL}	N WWW.	out!	0.8	TI	0.8	W	0.8	07.C	0.8	V
V _{IH}	W WWW.	2,4	COM	2,4	-	2.4	N.	2.4	03	V
High),	V _{IN} = 0V or + 15V	N.100	±1	M.T	±1	- 1	±1	.10ŪY	C±1	μА
	See Tables 1 and 3	Binary/Offset Binary			iry	Binary/Offset Binary				Will
N.C.	(Note 4)	-1×N.3	4	Mon	4	-	4	W-10	4	pF
ARACTER	ISTICS	W Taxi	1007.	~ON	LTW		M.	1.W.1	001.	Mo
Power Supply Voltage Range (Note 6)		+5 to +16		M.TV	+5 to		+16		V	
100X	All Digital Inputs High or Low (Excluding Ladder Network)	MM	200	V.C.	2.5	N	2	NWV	2.5	mA
	COUT1 COUT2 COUT2 COUT2 VIL WIH High),	COUT1 (Note 4) COUT2 All Digital Inputs High (Note 4) COUT1 All Digital Inputs Low (Note 4) /IL VIH High), V _{IN} = 0V or + 15V See Tables 1 and 3 (Note 4) ARACTERISTICS Range (Note 6) All Digital Inputs High or Low (Excluding Ladder	COUT1	TA 25°C MIN MAX	TA 25°C TA MIN MAX MIN MAX MIN	TA 25°C TA MIN-MAX MIN MAX MIN MAX	TA 25°C	T _A 25°C T _A MIN-MAX T _A 25°C MIN MAX MIN MAX MIN MAX COUT1	TA 25°C TA MIN-MAX TA 25°C TA MIN	TEST CONDITIONS Ta 25°C Ta MIN-Max Ta 25°C Ta MIN-Max

NOTES:

- 2. Full Scale Range (FSR) is 10V for unipolar and ±10V for bipolar modes.
- 3. Using internal feedback resistor, RFEEDBACK.
- 4. Guaranteed by design or characterization and not production tested.
- 5. Accuracy not guaranteed unless outputs at ground potential.
- 6. Accuracy is tested and guaranteed at V+ = +15V, only.

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Definition of Terms

Nonlinearity: Error contributed by deviation of the DAC transfer function from a "best straight line" through the actual plot of transfer function. Normally expressed as a percentage of full scale range or in (sub)multiples of 1 LSB.

Resolution: It is addressing the smallest distinct analog output change that a D/A converter can produce. It is commonly expressed as the number of converter bits. A converter with resolution of n bits can resolve output changes of 2^{-N} of the full-scale range, e.g., 2^{-N} V_{REF} for a unipolar conversion. Resolution by no means implies linearity.

Settling Time: Time required for the output of a DAC to settle to within specified error band around its final value (e.g., $^1/_2$ LSB) for a given digital input change, i.e., all digital inputs LOW to HIGH and HIGH to LOW.

Gain Error: The difference between actual and ideal analog output values at full-scale range, i.e., all digital inputs at HIGH state. It is expressed as a percentage of full scale range or in (sub)multiples of 1 LSB.

Feedthrough Error: Error caused by capacitive coupling from V_{REF} to I_{OUT1} with all digital inputs LOW.

Output Capacitance: Capacitance from I_{OUT1} , and I_{OUT2} terminals to ground.

Output Leakage Current: Current which appears on I_{OUT1} , terminal when all digital inputs are LOW or on I_{OUT2} terminal when all digital inputs are HIGH.

For further information on the use of this device, see the following Application Notes:

NOTE #	DESCRIPTION	AnswerFAX DOC. #	
AN002	"Principles of Data Acquisition and Conversion"	9002	
AN018	"Do's and Don'ts of Applying A/D Converters"	9018	
AN042	"Interpretation of Data Conversion Accuracy Specifications"	9042	

Detailed Description

The AD7523 and AD7533 are monolithic multiplying D/A converters. A highly stable thin film R-2R resistor ladder network and NMOS SPDT switches form the basis of the converter circuit, CMOS level shifters permit low power TTL/CMOS compatible operation. An external voltage or current reference and an operational amplifier are all that is required for most voltage output applications.

A simplified equivalent circuit of the DAC is shown in the Functional Diagram. The NMOS SPDT switches steer the ladder leg currents between I_{OUT1} and I_{OUT2} buses which must be held at ground potential. This configuration maintains a constant current in each ladder leg independent of the input code.

Converter errors are further reduced by using separate metal interconnections between the major bits and the outputs. Use of high threshold switches reduce offset (leakage) errors to a negligible level.

The level shifter circuits are comprised of three inverters with positive feedback from the output of the second to the first, see Figure 1. This configuration results in TTL/CMOS compatible operation over the full military temperature range. With the ladder SPDT switches driven by the level shifter, each switch is binarily weighted for an ON resistance proportional to the respective ladder leg current. This assures a constant voltage drop across each switch, creating equipotential terminations for the 2R ladder resistors and high accurate leg currents.

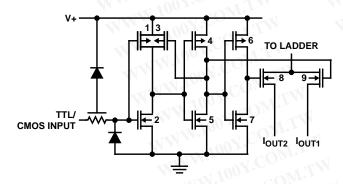
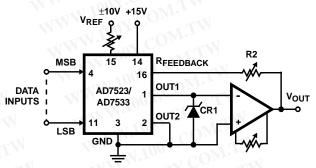


FIGURE 1. CMOS SWITCH

Typical Applications

Unipolar Binary Operation - AD7523 (8-Bit DAC)

The circuit configuration for operating the AD7523 in unipolar mode is shown in Figure 2. With positive and negative V_{REF} values the circuit is capable of 2-Quadrant multiplication. The "Digital Input Code/Analog Output Value" table for unipolar mode is given in Table 1.



NOTES:

- 1. R1 and R2 used only if gain adjustment is required.
- 2. CF1 protects AD7523 and AD7533 against negative transients.

FIGURE 2. UNIPOLAR BINARY OPERATION

TABLE 1. UNIPOLAR BINARY CODE - AD7523

DIGITAL INPUT MSB LSB	ANALOG OUTPUT
11111111	$-V_{REF}\left(\frac{255}{256}\right)$
10000001	$-V_{REF}(\frac{129}{256})$
10000000	$-V_{REF}\left(\frac{128}{256}\right) = -\frac{V_{REF}}{2}$
01111111	$-V_{REF}\left(\frac{127}{256}\right)$
0000001	$^{-V}$ REF $\left(\frac{1}{256}\right)$
00000000	$-V_{REF}\left(\frac{0}{256}\right) = 0$

NOTE:

1. 1 LSB =
$$(2^{-8})(V_{REF}) = (\frac{1}{256})(V_{REF})$$
.

Zero Offset Adjustment

- 1. Connect all digital inputs to GND.
- Adjust the offset zero adjust trimpot of the output operational amplifier for 0V ±1mV (Max) at V_{OUT}.

Gain Adjustment

- 1. Connect all digital inputs to V+.
- 2. Monitor VOLIT for a -VREF (1¹/₂⁸) reading.
- 3. To increase V_{OUT} , connect a series resistor, R2, (0 Ω to 250 Ω) in the I_{OUT1} amplifier feedback loop.
- 4. To decrease V_{OUT} , connect a series resistor, R1, (0 Ω to 250 Ω) between the reference voltage and the V_{REF} terminal.

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Unipolar Binary Operation - AD7533 (10-Bit DAC)

The circuit configuration for operating the AD7533 in unipolar mode is shown in Figure 2. With positive and negative V_{REF} values the circuit is capable of 2-Quadrant multiplication. The "Digital Input Code/Analog Output Value" table for unipolar mode is given in Table 2.

TABLE 2. UNIPOLAR BINARY CODE - AD7533

DIGITAL INPUT MSB LSB	(NOTE 1) NOMINAL ANALOG OUTPUT
1111111111	$-V_{REF}\left(\frac{1023}{1024}\right)$
100000001	$-V_{REF}\left(\frac{513}{1024}\right)$
100000000	$-V_{REF}\left(\frac{512}{1024}\right) = -\frac{V_{REF}}{2}$
011111111	$-V_{REF}\left(\frac{511}{1024}\right)$
000000001	$-V_{REF}\left(\frac{1}{1024}\right)$
000000000	$-V_{REF}\left(\frac{0}{1024}\right) = 0$

NOTES:

- 1. V_{OUT} as shown in the Functional Diagram.
- 2. Nominal Full Scale for the circuit of Figure 2 is given by:

$$FS = -V_{REF} \left(\frac{1023}{1024} \right)$$

3. Nominal LSB magnitude for the circuit of Figure 2 is given by:

LSB =
$$V_{REF} \left(\frac{1}{1024} \right)$$
.

Zero Offset Adjustment

- 1. Connect all digital inputs to GND.
- 2. Adjust the offset zero adjust trimpot of the output operational amplifier for 0V ±1mV (Max) at VOLIT

Gain Adjustment

- 1. Connect all digital inputs to V+.
- 2. Monitor V_{OUT} for a -V_{REF} (1 1/2¹⁰) reading

- 3. To increase V_{OUT} , connect a series resistor, R2, (0 Ω to 250 Ω) in the I_{OUT1} amplifier feedback loop.
- 4. To decrease V_{OUT} , connect a series resistor, R1, (0 Ω to 250 Ω) between the reference voltage and the V_{REF} terminal.

Bipolar (Offset Binary) Operation - AD7523

The circuit configuration for operating the AD7523 in the bipolar mode is given in Figure 3. Using offset binary digital input codes and positive and negative reference voltage values, Four-Quadrant multiplication can be realized. The "Digital Input Code/Analog Output Value" table for bipolar mode is given in Table 3.)

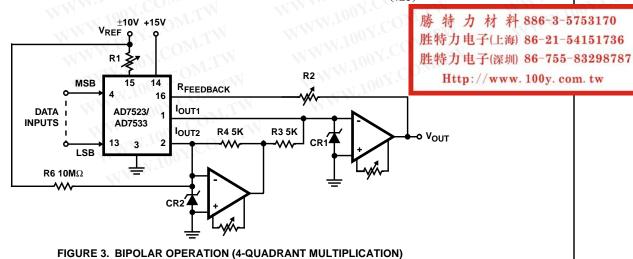
A "Logic 1" input at any digital input forces the corresponding ladder switch to steer the bit current to I_{OUT1} bus. A "Logic 0" input forces the bit current to I_{OUT2} bus. For any code the I_{OUT1} and I_{OUT2} bus currents are complements of one another. The current amplifier at I_{OUT2} changes the polarity of I_{OUT2} current and the transconductance amplifier at I_{OUT} output sums the two currents. This configuration doubles the output range. The difference current resulting at zero offset binary code, (MSB = "Logic 1", all other bits = "Logic 0"), is corrected by suing an external resistor, (10M Ω), from V_{REF} to I_{OUT2} (Figure 3).

TABLE 3. BIPOLAR (OFFSET BINARY) CODE - AD7523

DIGITAL INPUT MSB LSB	ANALOG OUTPUT
11111111	$-V_{REF}\left(\frac{127}{128}\right)$
10000001	$-V_{REF}\left(\frac{1}{128}\right)$
10000000	0
01111111	$+V_{REF}\left(\frac{1}{128}\right)$
0000001	$+V_{REF}(\frac{127}{128})$
00000000	$+V_{REF}\left(\frac{128}{128}\right)$

NOTE:

1.
$$1 LSB = (2^{-7})(V_{REF}) = (\frac{1}{128})(V_{REF})$$



Offset Adjustment

- 1. Adjust V_{REF} to approximately +10V.
- 2. Connect all digital inputs to "Logic 1"
- 3. Adjust I $_{OUT2}$ amplifier offset adjust trimpot for 0V ± 1 mV at I $_{OUT2}$ amplifier output.
- 4. Connect MSB (Bit 1) to "Logic 1" and all other bits to "Logic 0".
- 5. Adjust I_{OUT1} amplifier offset adjust trimpot for $0V \pm 1mV$ at V_{OUT} .

Gain Adjustment

- 1. Connect all digital inputs to V+.
- 2. Monitor V_{OUT} for a -V_{REF} (1¹/₂⁸) volts reading.
- 3. To increase V_{OUT} , connect a series resistor, R2, of up to 250Ω between V_{OUT} and $R_{FEEDBACK}$.
- 4. To decrease V_{OUT} , connect a series resistor, R1, of up to 250Ω between the reference voltage and the V_{REF} terminal.

Bipolar (Offset Binary) Operation - AD7533

The circuit configuration for operating the AD7533 in the bipolar mode is given in Figure 3. Using offset binary digital input codes and positive and negative reference voltage values, 4-Quadrant multiplication can be realized. The "Digital Input Code/Analog Output Value" table for bipolar mode is given in Table 4.

A "Logic 1" input at any digital input forces the corresponding ladder switch to steer the bit current to I_{OUT1} bus. A "Logic 0" input forces the bit current to I_{OUT2} bus. For any code the I_{OUT1} and I_{OUT2} bus currents are complements of one

another. The current amplifier at I_{OUT2} changes the polarity of I_{OUT2} current and the transconductance amplifier at I_{OUT1} output sums the two currents. This configuration doubles the output range. The difference current resulting at zero offset binary code, (MSB = "Logic 1", all other bits = "Logic 0"), is corrected by using an external resistor, (10M Ω), from V_{REF} to I_{OUT2} .

TABLE 4. UNIPOLAR BINARY CODE - AD7533

DIGITAL INPUT MSB LSB	(NOTE 1) NOMINAL ANALOG OUTPUT
111111111	$-V_{REF}\left(\frac{511}{512}\right)$
100000001	$-V_{REF}\left(\frac{1}{512}\right)$
100000000	0.100Y.COM.TW
0111111111	$+V_{REF}\left(\frac{1}{512}\right)$
000000001	$^{+V}_{REF} \left(\frac{511}{512} \right)$
0000000000	$+V_{REF}(\frac{512}{512})$

NOTES:

- 1. VOLIT as shown in the Functional Diagram.
- 2. Nominal Full Scale for the circuit of Figure 6 is given by:

$$FSR = V_{REF} \left(\frac{1023}{512} \right).$$

3. Nominal LSB magnitude for the circuit of Figure 3 is given by:

LSB =
$$V_{REF} \left(\frac{1}{512} \right)$$

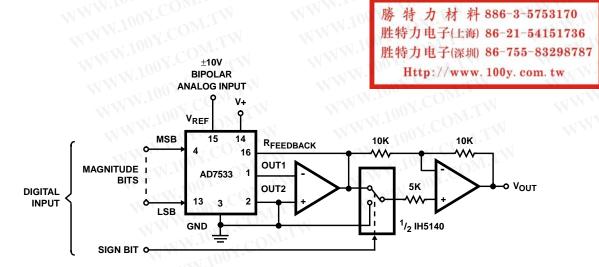


FIGURE 4. 10-BIT AND SIGN MULTIPLYING DAC

Offset Adjustment

- 1. Adjust V_{REF} to approximately +10V.
- 2. Connect all digital inputs to "Logic 1".
- 3. Adjust I_{OUT2} amplifier offset adjust trimpot for 0V ± 1 mV at I_{OUT2} amplifier output.
- 4. Connect MSB (Bit 1) to "Logic 1" and all other bits to "Logic 0".
- Adjust I_{OUT1} amplifier offset adjust trimpot for 0V ±1mV at V_{OUT}.

Gain Adjustment

- 1. Connect all digital inputs to V+.
- 2. Monitor V_{OUT} for a -V_{REF} (1 2⁻⁹) volts reading.
- 3. To increase V_{OUT} , connect a series resistor of up to 250 Ω between V_{OUT} and $R_{FEEDBACK}$.
- 4. To decrease V_{OUT} , connect a series resistor of up to 250Ω between the reference voltage and the V_{REF} terminal.

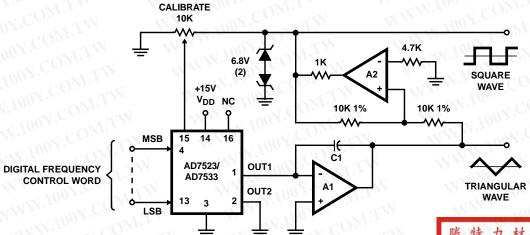
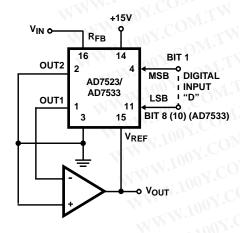


FIGURE 5. PROGRAMMABLE FUNCTION GENERATOR

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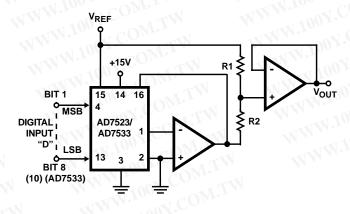
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$$D = \frac{Bit \ 1}{2^1} + \frac{Bit \ 2}{2^2} + \dots \frac{Bit \ 8}{2^2}$$

$$\left(0 \le D \le \frac{255}{256}\right)$$

FIGURE 6. DIVIDER (DIGITALLY CONTROLLED GAIN)



$$V_{OUT} = V_{REF} \left[\frac{R_2}{R_1 + R_2} - \left(\frac{R_1 D}{R_1 + R_2} \right) \right]$$

Where D =
$$\frac{\text{Bit 1}}{2^1} + \frac{\text{Bit 2}}{2^2} + \dots \frac{\text{Bit 8}}{2^8}$$

$$\left(0 \le D \le \frac{255}{256}\right)$$

FIGURE 7. MODIFIED SCALE FACTOR AND OFFSET

Die Characteristics

DIE DIMENSIONS:

101 mils x 103 mils (2565micrms x 2616micrms)

METALLIZATION:

Type: Pure Aluminum Thickness: 10 ±1kÅ

PASSIVATION:

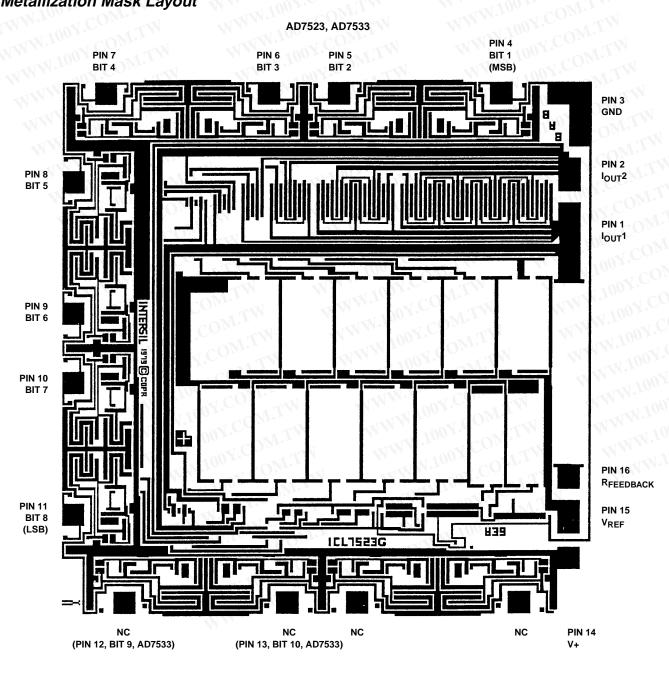
Type: PSG/Nitride PSG: 7 ±1.4kÅ Nitride: 8 ±1.2kÅ

PROCESS:

CMOS Metal Gate

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Metallization Mask Layout



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